



PATENT
2804-0102P

IN THE U.S. PATENT AND TRADEMARK OFFICE

Applicant: Takashi MORISHITA et al. Conf.: 9853
Appl. No.: 09/787,877 Group: 2822
Filed: March 23, 2001 Examiner: Ida Soward
For: SEMICONDUCTOR SUBSTRATE AND PRODUCTION METHOD
THEREOF, SEMICONDUCTOR DEVICE USING THE SAME AND
PRODUCTION METHOD THEREOF

REPLY UNDER 37 C.F.R. § 1.111

Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

November 24, 2003

Sir:

In reply to the Office Action dated September 10, 2003, the following remarks are respectfully submitted in connection with the above-identified application.

RECEIVED
REC-5 2003
TECHNOLOGY CENTER 2003